Quad buffer/line driver; 3-state

Rev. 1 — 15 November 2013

Product data sheet

1. General description

The 74VHC126-Q100; 74VHCT126-Q100 are high-speed Si-gate CMOS devices and are pin compatible with Low-power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard No. 7-A.

The 74VHC126-Q100; 74VHCT126-Q100 provide four non-inverting buffer/line drivers with 3-state outputs. The output enable input (nOE) controls the 3-state outputs (nY). A LOW-level at pin nOE causes the outputs to assume a high-impedance OFF-state.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Specified from -40 °C to +85 °C and from -40
- Balanced propagation delays
- All inputs have Schmitt-trigger action
- Inputs accept voltages higher than V_{CC}
- Input levels:
 - The 74VHC126-Q100 operates with CMOS input level
 - ◆ The 74VHCT126-Q100 operates with TTL input level
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pf, R = 0 Ω)
- Multiple package options

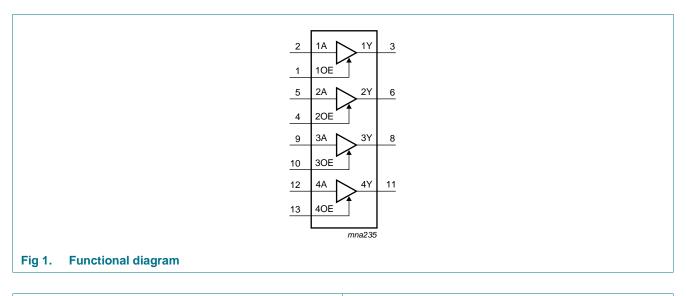


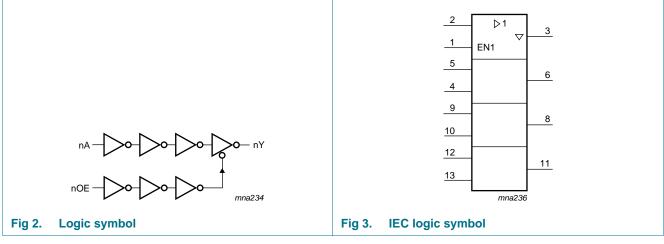
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3. Ordering information

Table 1. Ordering in	formation			
Type number	Package			
	Temperature range	Name	Description	Version
74VHC126D-Q100	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads;	SOT108-1
74VHCT126D-Q100			body width 3.9 mm	
74VHC126PW-Q100	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package;	SOT402-1
74VHCT126PW-Q100			14 leads; body width 4.4 mm	
74VHC126BQ-Q100	–40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced	SOT762-1
74VHCT126BQ-Q100			very thin quad flat package; no leads; 14 terminals; body $2.5 \times 3 \times 0.85$ mm	

4. Functional diagram

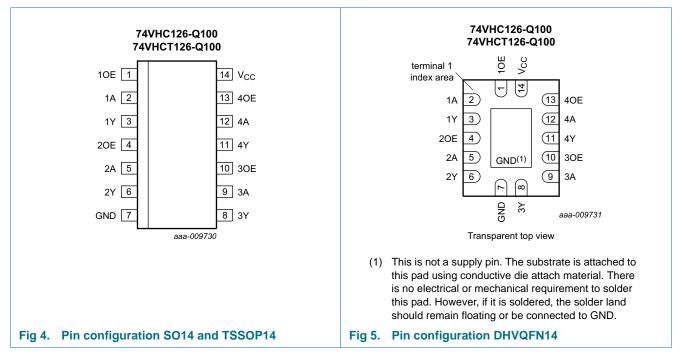




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5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
10E	1	output enable input 1 (active HIGH)
1A	2	data input 1
1Y	3	data output 1
2OE	4	output enable input 2 (active HIGH)
2A	5	data input 2
2Y	6	data output 2
GND	7	ground (0 V)
3Y	8	data output 3
ЗA	9	data input 3
3OE	10	output enable input 3 (active HIGH)
4Y	11	data output 4
4A	12	data input 4
40E	13	output enable input 4 (active HIGH)
V _{CC}	14	supply voltage

6. Functional description

Table 3.	Function table ^[1]		
Control		Input	Output
nOE		nA	nY
Н		L	L
Н		Н	Н
L		Х	Z

[1] H = HIGH voltage state;

L = LOW voltage state;

X = don't care;

Z = high-impedance OFF-state.

7. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I _{IK}	input clamping current	V _I < -0.5 V	<u>[1]</u> –20	-	mA
Ι _{ΟΚ}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> –20	+20	mA
lo	output current	$V_{O} = -0.5 \text{ V}$ to ($V_{CC} + 0.5 \text{ V}$)	-25	+25	mA
I _{CC}	supply current		-	+75	mA
I _{GND}	ground current		-75	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to +125 \ ^{\circ}C$	[2] _	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SO14 packages: above 70 °C the value of P_{tot} derates linearly at 8 mW/K.

For TSSOP14 packages: above 60 °C the value of P_{tot} derates linearly at 5.5 mW/K. For DHVQFN14 packages: above 60 °C the value of P_{tot} derates linearly at 4.5 mW/K.

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8. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
74VHC126-Q1	00					
V _{CC}	supply voltage		2.0	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V_{CC} = 3.0 V to 3.6 V	-	-	100	ns/V
		V_{CC} = 4.5 V to 5.5 V	-	-	20	ns/V
74VHCT126-Q	100					
V _{CC}	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$	-	-	20	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C 1	to +85 °C	–40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74VHC12	26-Q100		•							
VIH	HIGH-level	V _{CC} = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
inp	input voltage	V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V _{IL} LOW-level input voltage		V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	0.9	V	
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$								
		$I_{O} = -50 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -50 \ \mu A; \ V_{CC} = 3.0 \ V$	2.9	3.0	-	2.9	-	2.9	-	V
		$I_{O} = -50 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	V
		$I_{O} = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.80	-	3.70	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_0 = 50 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 50 \ \mu A; \ V_{CC} = 3.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 50 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.36	-	0.44	-	0.55	V
		I _O = 8.0 mA; V _{CC} = 4.5 V	-	-	0.36	-	0.44	-	0.55	V

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Symbol	Parameter	Conditions		25 °C		–40 °C	to +85 °C	–40 °C t	to +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
lı	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
l _{oz}	OFF-state output current		-	-	±0.25	-	±2.5	-	±10.0	μA
I _{CC}	supply current		-	-	2.0	-	20	-	40	μA
Cı	input capacitance	$V_{I} = V_{CC}$ or GND	-	3	10	-	10	-	10	pF
Co	output capacitance		-	4	-	-	-	-	-	pF
74VHCT	126-Q100									
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
	HIGH-level	V_{I} = V_{IH} or $V_{IL};V_{CC}$ = 4.5 V								
	output voltage	I _O = -50 μA	4.4	4.5	-	4.4	-	4.4	-	
		I _O = -8.0 mA	3.94	-	-	3.80	-	3.70	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$								
	output voltage	I _O = 50 μA	-	0	0.1	-	0.1	-	0.1	V
		l _O = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V
I	input leakage current	$V_I = 5.5 V \text{ or GND};$ $V_{CC} = 0 V \text{ to } 5.5 V$	-	-	0.1	-	1.0	-	2.0	μA
l _{oz}	OFF-state output current		-	-	±0.25	-	±2.5	-	±10.0	μA
I _{CC}	supply current		-	-	2.0	-	20	-	40	μA
∆I _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$; other pins at V_{CC} or GND; $I_0 = 0 \text{ A}$; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
CI	input capacitance	$V_{I} = V_{CC}$ or GND	-	3	10	-	10	-	10	pF
Co	output capacitance		-	4	-	-	-	-	-	pF

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

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10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit, see <u>Figure 8</u>.

Symbol	Parameter	Conditions			25 °C		-40 °C	to +85 °C	−40 °C	to +125 °C	Uni
				Min	Typ <mark>[1]</mark>	Max	Min	Max	Min	Max	
74VHC1	26-Q100										
t _{pd}	propagation	nA to nY; see Figure 6	[2]								
	delay	V_{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	4.7	8.0	1.0	9.5	1.0	10.0	ns
		C _L = 50 pF		-	6.7	11.5	1.0	13.0	1.0	14.5	ns
		V_{CC} = 4.5 V to 5.5 V									
		C _L = 15 pF		-	3.3	5.5	1.0	6.5	1.0	7.0	ns
	C _L = 50 pF		-	4.7	7.5	1.0	8.5	1.0	9.5	ns	
t _{en}	enable time	nOE to nY; see Figure 7	[3]								
		V_{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	5.3	8.0	1.0	9.5	1.0	10.0	ns
		C _L = 50 pF		-	7.6	11.5	1.0	13.0	1.0	14.5	ns
		V_{CC} = 4.5 V to 5.5 V									
		C _L = 15 pF		-	3.6	5.3	1.0	6.1	1.0	7.0	ns
		C _L = 50 pF		-	5.1	7.6	1.0	8.7	1.0	9.5	ns
t _{dis} disable	disable time	nOE to nY; see Figure 7	[4]								
		V_{CC} = 3.0 V to 3.6 V									
		C _L = 15 pF		-	6.6	9.7	1.0	11.5	1.0	12.5	ns
		C _L = 50 pF		-	9.4	13.2	1.0	15.0	1.0	16.5	ns
		V_{CC} = 4.5 V to 5.5 V									
		C _L = 15 pF		-	4.7	6.8	1.0	8.0	1.0	8.5	ns
		C _L = 50 pF		-	6.7	8.8	1.0	10.0	1.0	11.0	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz};$ V ₁ = GND to V _{CC}	<u>[5]</u>	-	10	-	-	-	-	-	pF
74VHCT	126-Q100; V _C	_C = 4.5 V to 5.5 V									
t _{pd}	propagation	nA to nY; see Figure 6	[2]								
	delay	C _L = 15 pF		-	3.0	5.5	1.0	6.5	1.0	7.0	ns
		C _L = 50 pF		-	4.3	7.5	1.0	8.5	1.0	9.5	ns
t _{en}	enable time	nOE to nY; see Figure 7	[3]								
		C _L = 15 pF		-	3.3	5.1	1.0	6.0	1.0	6.5	ns
		C _L = 50 pF		-	4.7	7.1	1.0	8.0	1.0	9.0	ns
t _{dis}	disable time	nOE to nY; see Figure 7	[4]								ns ns ns ns ns ns ns ns ns ns pF
		C _L = 15 pF		-	4.8	6.8	1.0	8.0	1.0	8.5	ns
		C _L = 50 pF		-	6.9	8.9	1.0	10.0	1.0	11.5	ns
C _{PD}	power dissipation capacitance	$f_i = 1 \text{ MHz};$ V ₁ = GND to V _{CC}	[5]	-	12	-	-	-	-	-	

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- [1] Typical values are measured at nominal supply voltage (V_{CC} = 3.3 V and V_{CC} = 5.0 V).
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [3] t_{en} is the same as t_{PZL} and t_{PZH} .
- [4] t_{dis} is the same as t_{PLZ} and t_{PHZ} .

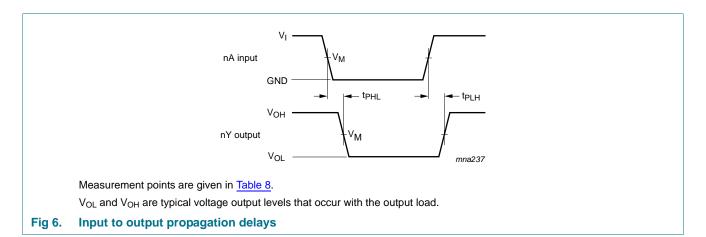
 C_L = output load capacitance in pF;

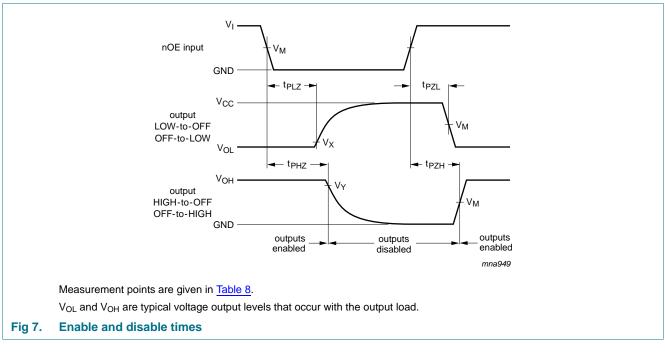
 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

11. Waveforms





74VHC_VHCT126_Q100

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Table 8. Measurement points							
Туре	Input	Output					
	V _M	V _M	V _X	V _Y			
74VHC126-Q100	0.5V _{CC}	0.5V _{CC}	V _{OL} + 0.3 V	$V_{OH} - 0.3 V$			
74VHCT126-Q100	1.5 V	0.5V _{CC}	V _{OL} + 0.3 V	V _{OH} – 0.3 V			

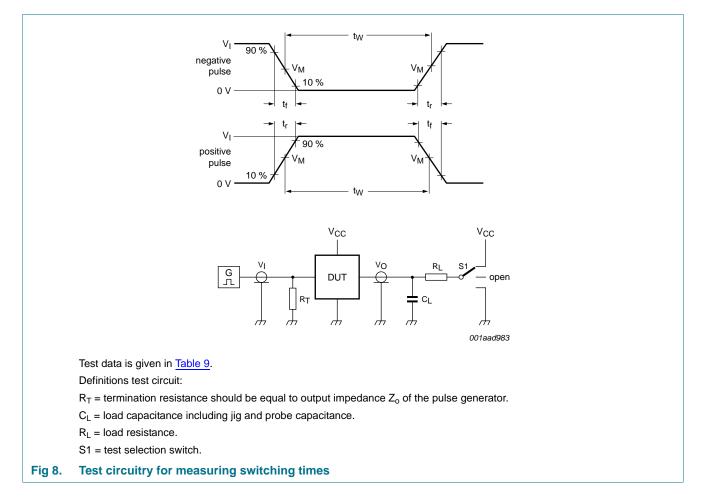


Table 9. Test data

Туре	Input		Load		S1 position			
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
74VHC126-Q100	V _{CC}	\leq 3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	
74VHCT126-Q100	3.0 V	\leq 3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}	

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12. Package outline

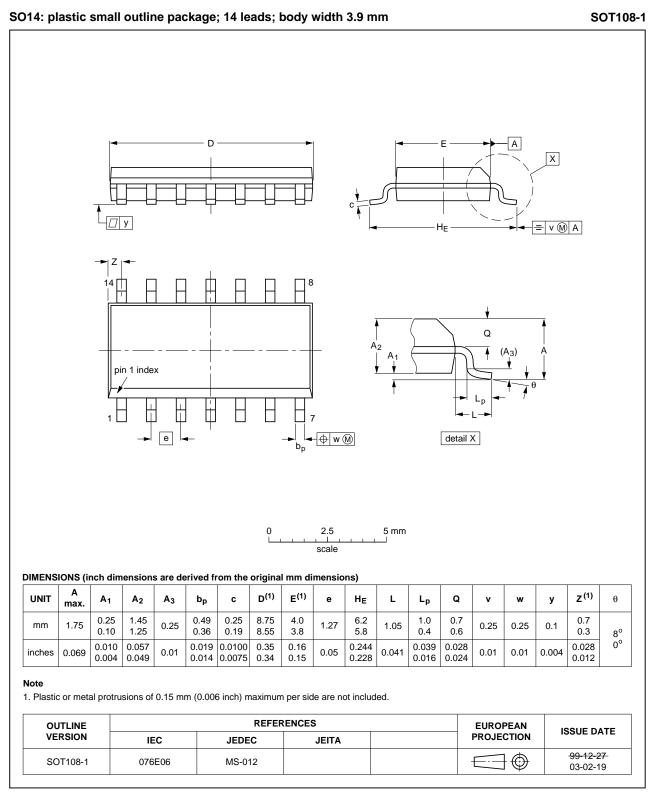


Fig 9. Package outline SOT108-1 (SO14)

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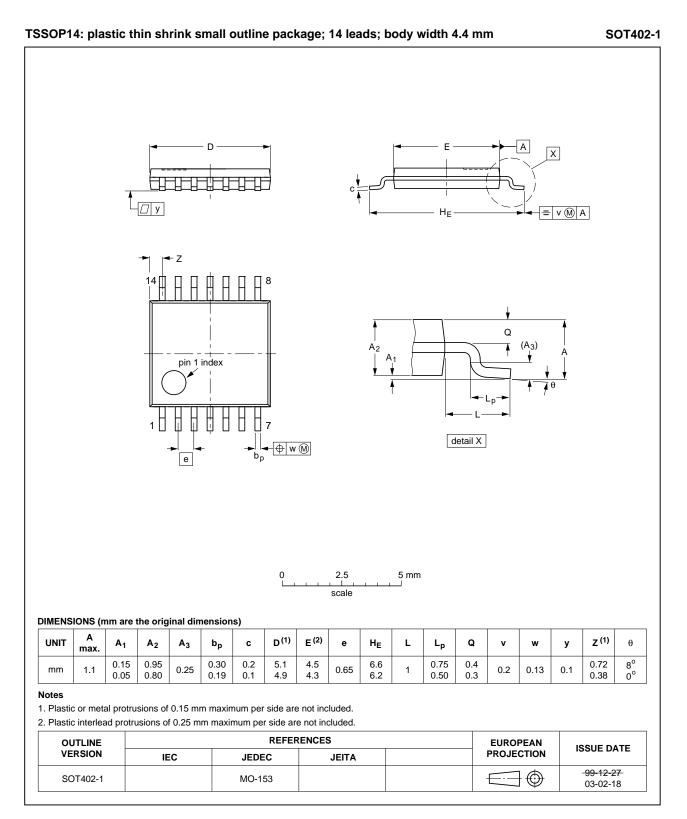
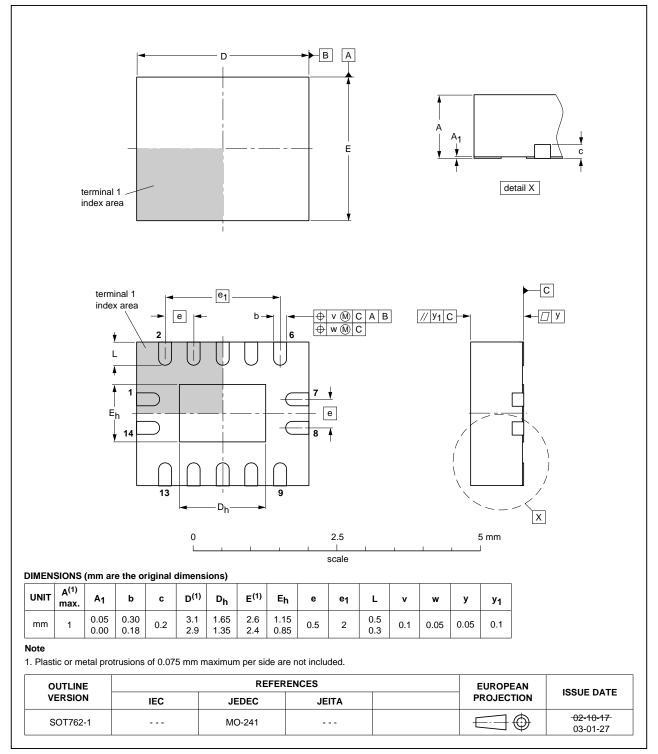


Fig 10. Package outline SOT402-1 (TSSOP14)

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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1

Fig 11. Package outline SOT762-1 (DHVQFN14)

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13. Abbreviations

Table 10.	Abbreviations
Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
LSTTL	Low-power Schottky Transistor-Transistor Logic
MIL	Military
MM	Machine Model

14. Revision history

Table 11.Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
74VHC_VHCT126_Q100 v.1	20131115	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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